Insulator-metal transitions in TMPX₃ van-der-Waals antiferromagnets

M.J. Coak 1,2,3*, C.R.S. Haines 1,4, D. Daisenberger 5, H. Hamidov 1,6,7, G.I. Lampronti 4, A.R. Wildes 8, S. Son 2,3, C. Liu 1, P. Nahai-Williamson 1, J-G. Park 2,3 and S.S. Saxena 1,7

¹Cavendish Laboratory, University of Cambridge, Cambridge, UK

²IBS-CCES, Seoul National University, Seoul, Republic of Korea

³Department of Physics and Astronomy, Seoul National University, Seoul, Republic of Korea

⁴Department of Earth Sciences, University of Cambridge, Cambridge, UK

⁵Diamond Light Source, Didcot, UK

⁶Navoiy Branch of the Academy of Sciences of Uzbekistan, Navoiy, Uzbekistan

⁷National University of Science and Technology 'MISiS', Moscow, Russia

⁸Institut Laue-Langevin, Grenoble, France

Keywords: High pressure, Diamond Anvils, Transport properties, Mott transitions, X-ray diffraction, Magnetism, Low-dimensional systems

*e-mail: mjc253@cam.ac.uk

The honeycomb two-dimensional antiferromagnets $TMPS_3$, where TM = Transition Metal such as Fe, Mn, Ni, V, form an ideal playground for tuning both low-dimensional magnetic and electronic properties. Electronically, these materials are all Mott insulators (see [1] for a review), with a wide range of band gaps from 0.2 to 3.5 eV across the family, and despite all sharing the same structure, these materials show a rich variety of 2D magnetic structures. The field of 2D magnetism is currently a very hot topic in condensed matter physics, with a flurry of high-impact publications, and the tuning of magnetic and electronic properties in such materials has exciting potential for new technological applications such as spintronics and a new generation of transistors.

I will present an overview of our work using high pressure as a continuous tuning parameter to control the dimensionality of these materials. Due to the weak physical inter-planar forces in such van-der-Waals materials, pressure gives us clean and selective control over the inter-planar spacing and hence interactions. I will present magnetic, structural and electrical transport results and compare the behaviour of Fe-, V-, Mn- and NiPS₃ as we tune them towards 3D structures.

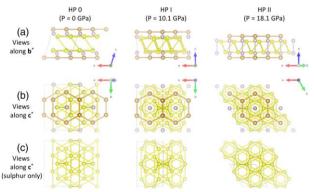


Figure 1. Structural evolution of FePS₃ with pressure. The second transition, to the HP-II phase, is accompanied by an insulator-metal transition.

Of particular interest is the contrast between the case of FePS₃ [2] and the near-unstudied VPS₃. We find 2 structural transitions with pressure common to the whole family, and link the second to an insulator-metal transition – except in the case of VPS₃ where we find the transition to be isostructural. Multiple puzzles persist in the very different transport and magnetotransport properties of Feand VPS₃.

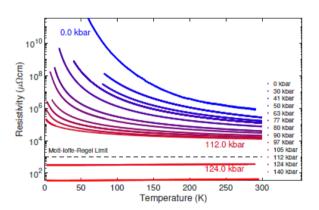


Figure 2. Insulator-metal transition in single-crystal VPS₃ as pressure is increased in a diamond-anvil cell.

Acknowledgments: This work was carried out with the support of the Diamond Light Source, Jesus College of the University of Cambridge, IHT KAZATOMPROM and the CHT Uzbekistan programme. The work was carried out with financial support from the Ministry of Education and Science of the Russian Federation. This work was supported by the Institute for Basic Science (IBS) in Korea (Grant No. IBS-R009-G1).

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